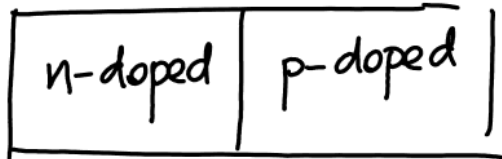


Semiconductor devices

Lecture 3 Semiconductors

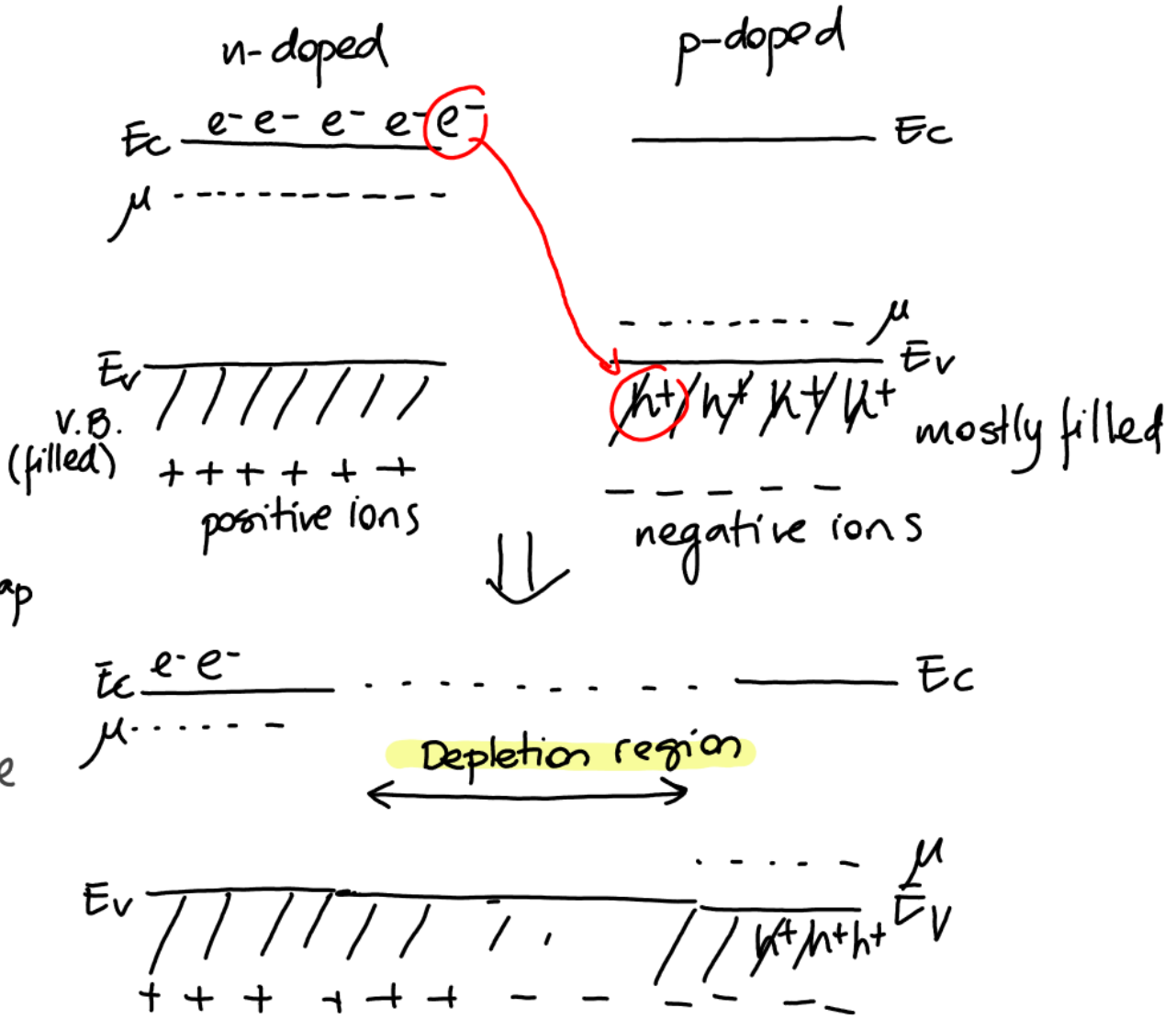
Recap

p-n Junction

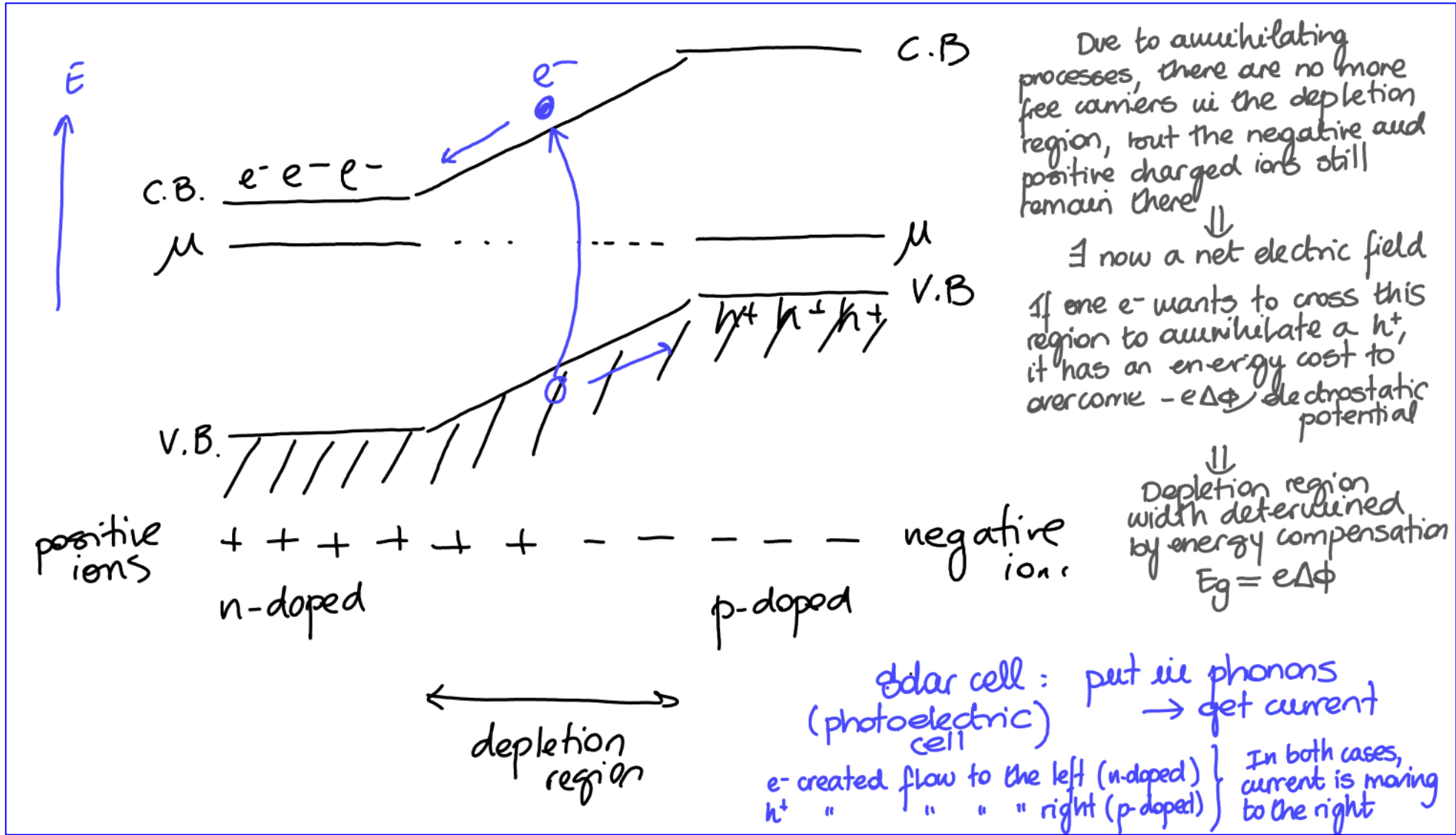


When the 2 materials are brought together, e^- in c.B. will fall in the v.B. to annihilate holes
 → this annihilating process gains an energy E_{gap}

As a result, there will be a region close to the interface where there are no more free carriers
 ⇒ "depletion region" or "space charge region"



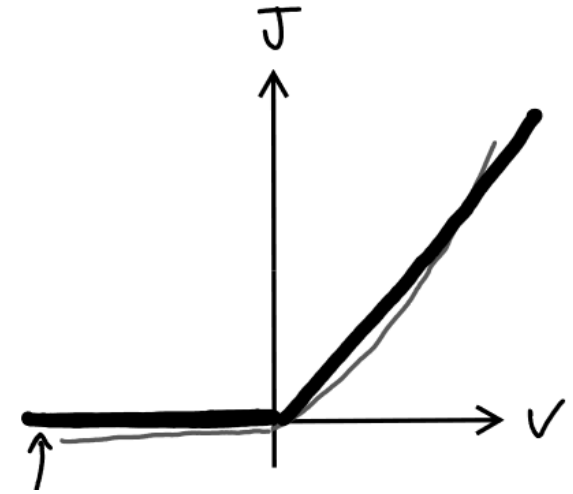
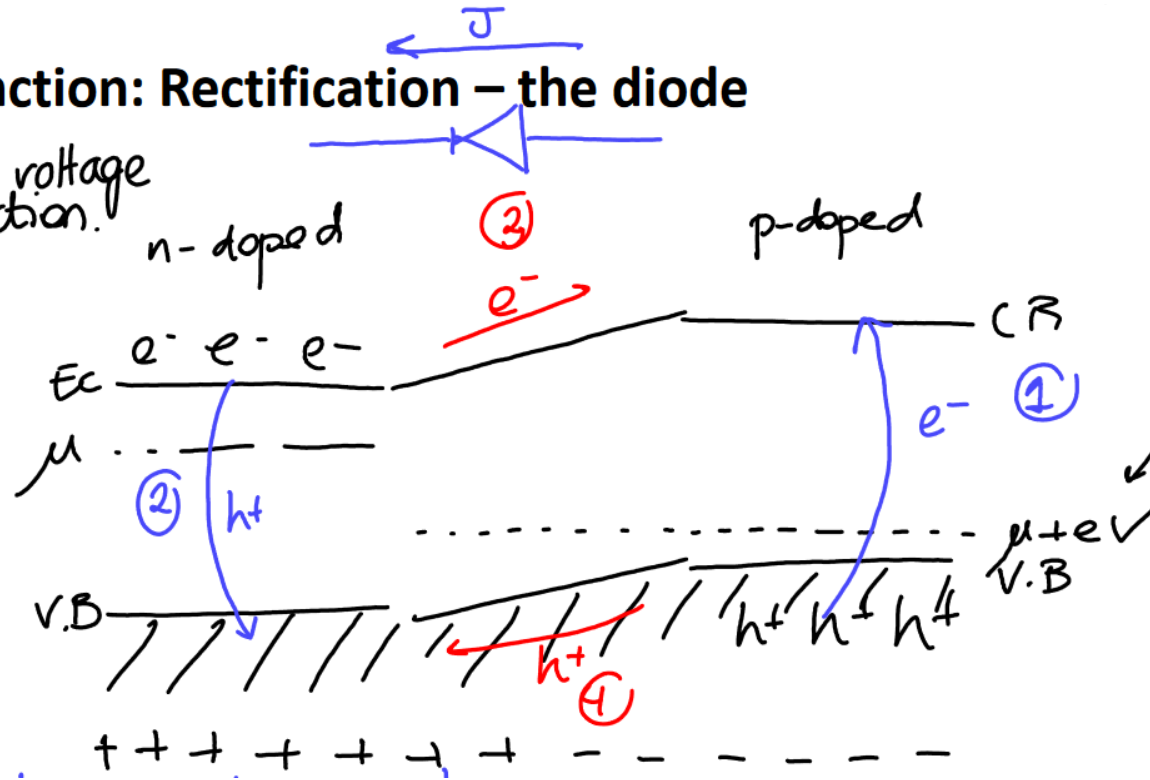
Recap



Recap

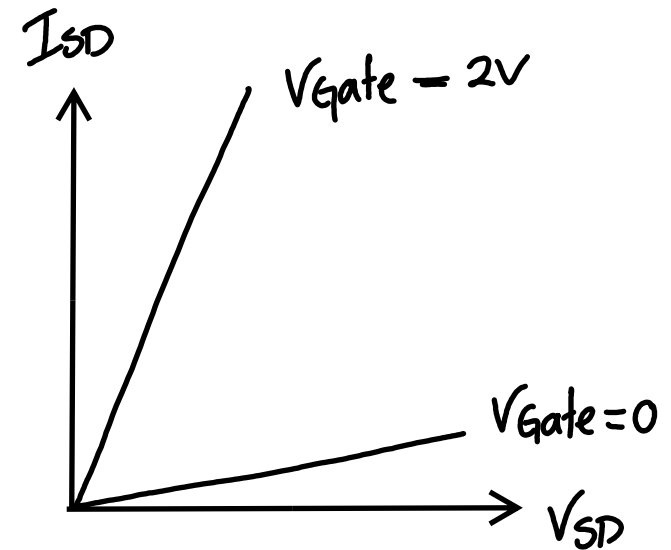
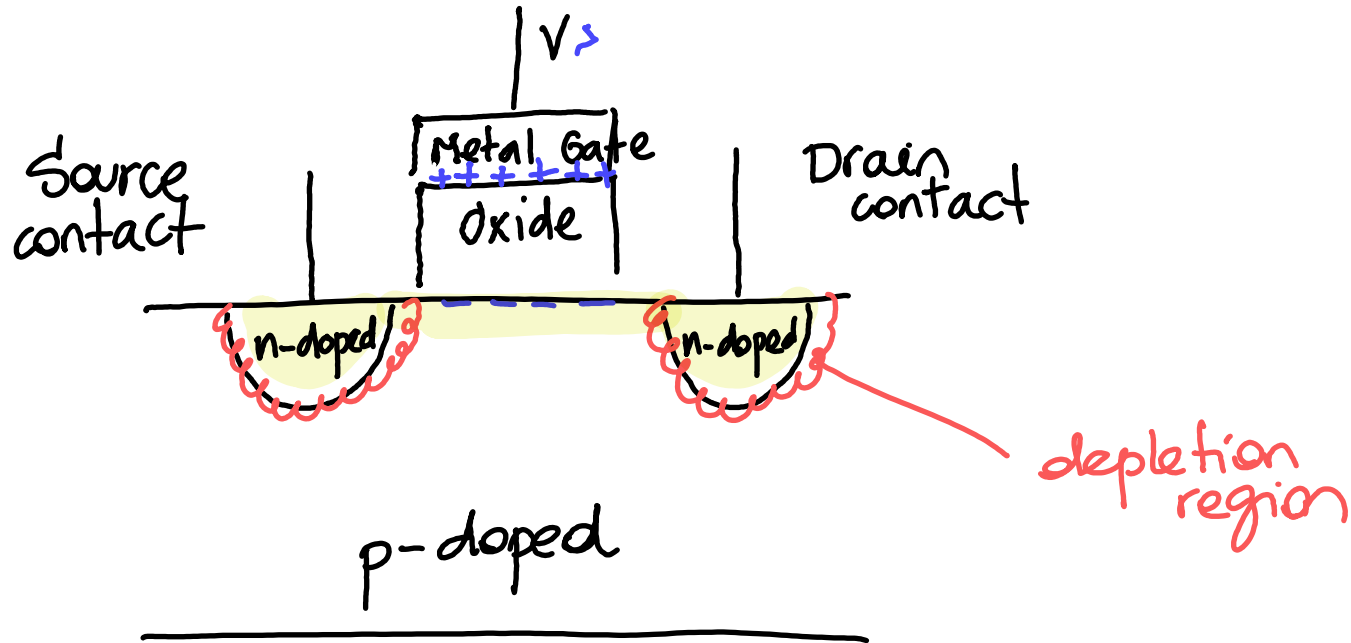
p-n Junction: Rectification – the diode

Let's apply a voltage to a pn junction.



The transistor

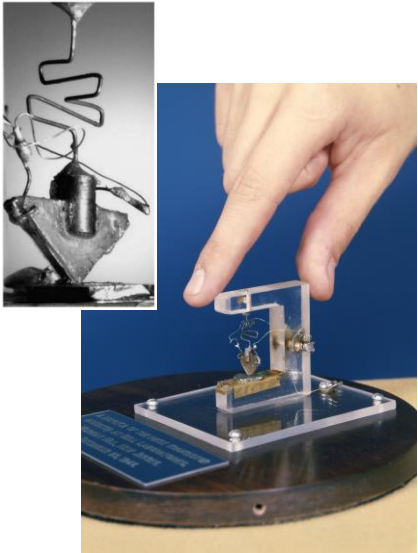
- there are many type of transistors
- Here, focus on MOSFET: "metal-oxide-semiconductor field effect transistor"



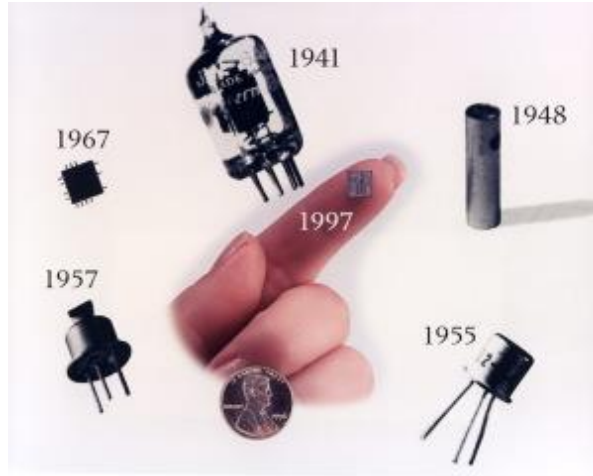
(i.e. Like back to back diodes)

- Without voltage in the gate, the current cannot flow easily between source - drain
- Positive voltage in the gate attracts negative charges below the oxide (field effect)
 - region below oxide layers becomes effectively n-doped
 - continuous conducting channel between source - drain is formed, where current can now flow.

The transistor - evolution

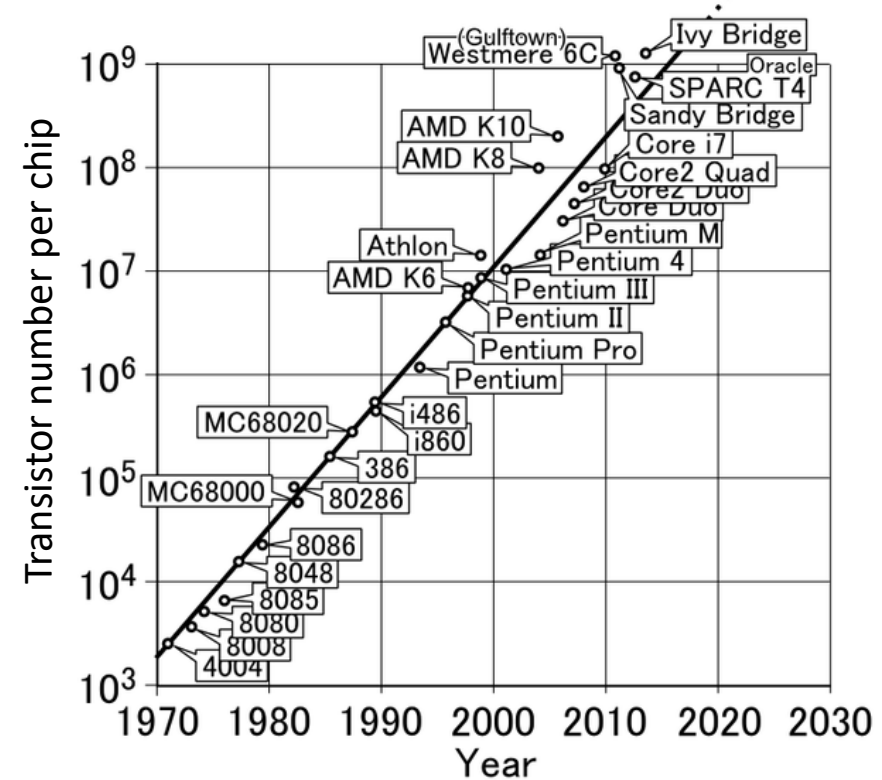


First transistor 1947

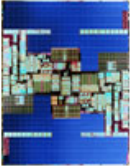



A **22nm** tri-gate transistor's is so small that you can fit more than **4000** of them across the width of a human hair! (Intel)

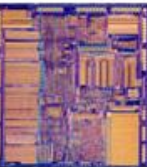
“Moore’s Observation”: “the number of transistors on integrated circuits doubles approximately every two

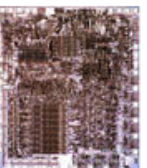


Creating new materials that exhibit enhanced or novel behaviours is essential to meet the technological challenges we face today!

2000s
64-bit
Microprocessor

592,000,000 Transistors

1990s
32-bit
Microprocessor

3,100,000 Transistors

1980s
32-bit
Microprocessor

275,000 Transistors

1970s
8-bit
Microprocessor

4500 Transistors